

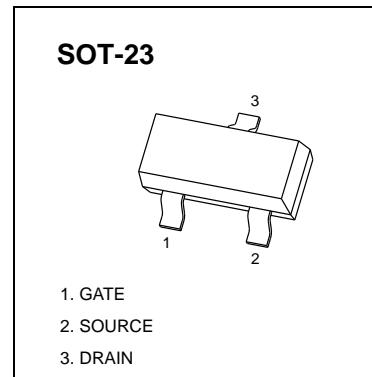
30V N-Channel MOSFET

Product Summary

- V_{DS} 30V
- I_D 5.6A
- $R_{DS(ON)}$ (at $V_{GS}=10V$) < 24mohm
- $R_{DS(ON)}$ (at $V_{GS}=4.5V$) < 38mohm
- 100% ∇V_{DS} Tested

General Description

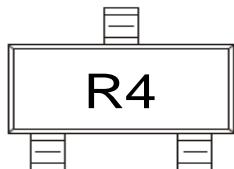
- Trench Power LV MOSFET technology
- High density cell design for low $R_{DS(ON)}$
- High Speed switching



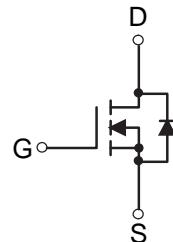
Applications

- Battery protection
- Load switch
- Power management

Marking: R4



Equivalent Circuit



■ Absolute Maximum Ratings ($T_A=25^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-source Voltage	V_{DS}	30	V
Gate-source Voltage	V_{GS}	± 20	V
Drain Current	I_D	5.6	A
		4.5	
Pulsed Drain Current ^A	I_{DM}	30	A
Total Power Dissipation	P_D	1.2	W
		0.8	W
Thermal Resistance Junction-to-Ambient ^B	$R_{\theta JA}$	104	$^\circ C / W$
Junction and Storage Temperature Range	T_J, T_{STG}	-55 ~ +150	$^\circ C$



FTK3404A

■ Electrical Characteristics ($T_J=25^\circ C$ unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static Parameter						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=250\mu A$	30			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=30V, V_{GS}=0V$			1	μA
Gate-Body Leakage Current	I_{GSS1}	$V_{GS}=\pm 20V, V_{DS}=0V$			± 100	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1	1.5	2.2	V
Static Drain-Source On-Resistance	$R_{DS(ON)}$	$V_{GS}=10V, I_D=5.6A$		17	24	$m\Omega$
		$V_{GS}=4.5V, I_D=5A$		26	38	
Diode Forward Voltage	V_{SD}	$I_S=5.6A, V_{GS}=0V$			1.2	V
Dynamic Parameters						
Input Capacitance	C_{iss}	$V_{DS}=15V, V_{GS}=0V, f=1MHz$		526		pF
Output Capacitance	C_{oss}			78		
Reverse Transfer Capacitance	C_{rss}			69		
Switching Parameters						
Total Gate Charge	Q_g	$V_{GS}=10V, V_{DS}=15V, I_D=5.6A$		12.22		nC
Gate-Source Charge	Q_{gs}			2.37		
Gate-Drain Charge	Q_{gd}			2.31		
Reverse Recovery Charge	Q_{rr}	$I_F=5.6A, dI/dt=100A/us$		1.28		ns
Reverse Recovery Time	t_{rr}			16.5		
Turn-on Delay Time	$t_{D(on)}$			5		
Turn-on Rise Time	t_r	$V_{GS}=10V, V_{DS}=15V, I_D=5.6A$ $R_{GEN}=3\Omega$		28.2		ns
Turn-off Delay Time	$t_{D(off)}$			12.8		
Turn-off fall Time	t_f			21.6		

A. Pulse Test: Pulse Width≤ 300us,Duty cycle ≤ 2%.

B. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design, while $R_{\theta JA}$ is determined by the board design. The maximum rating presented here is based on mounting on a 1 in 2 pad of 2oz copper.

■ Typical Performance Characteristics

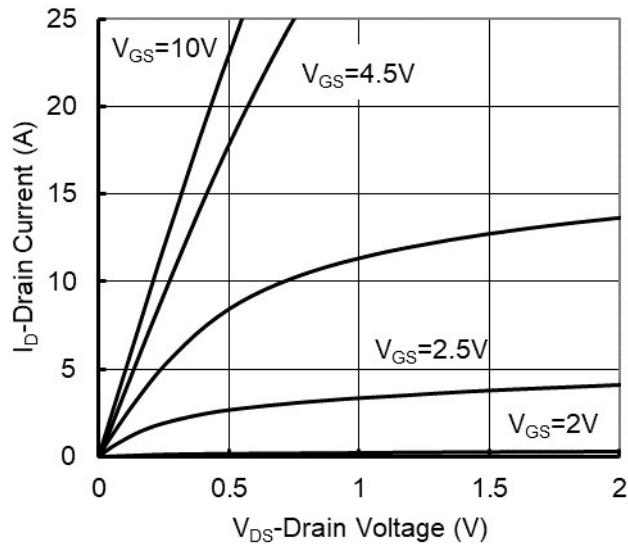


Figure 1. Output Characteristics

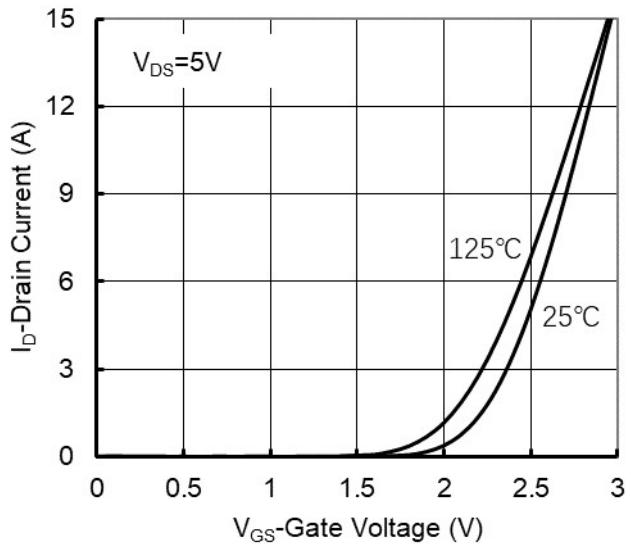


Figure 2. Transfer Characteristics

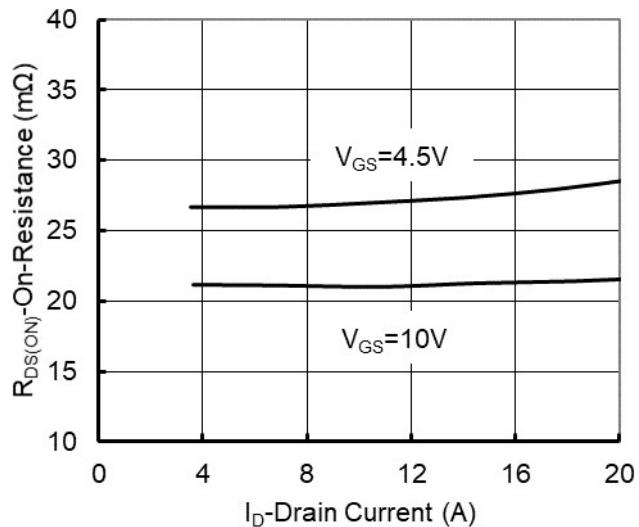


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

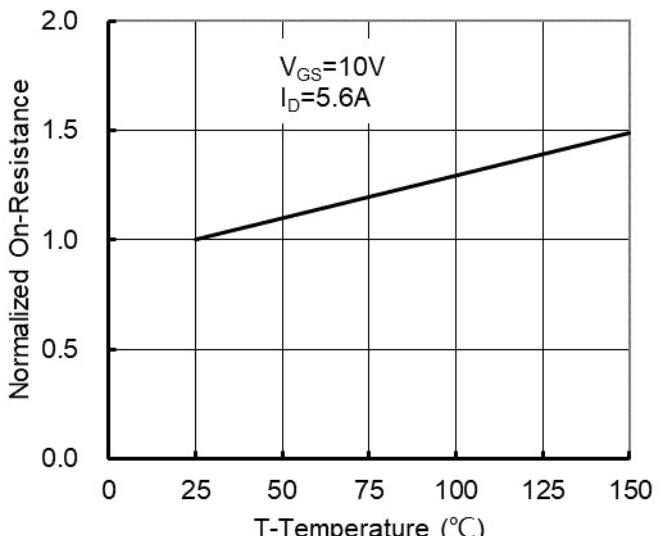


Figure 4: On-Resistance vs. Junction Temperature

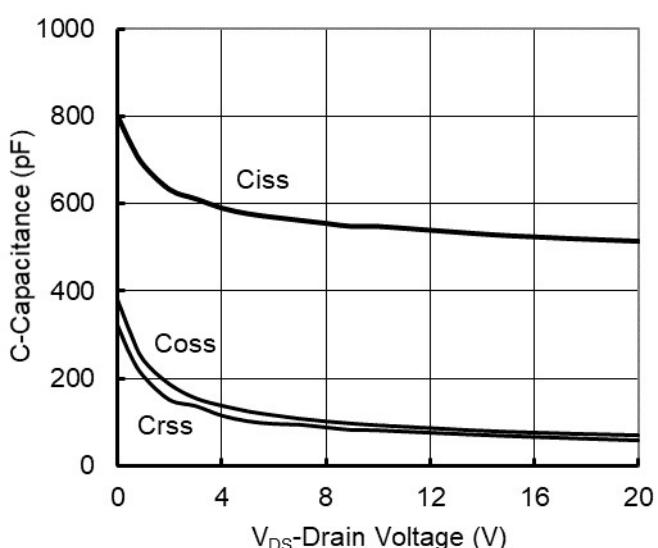


Figure 5. Capacitance Characteristics

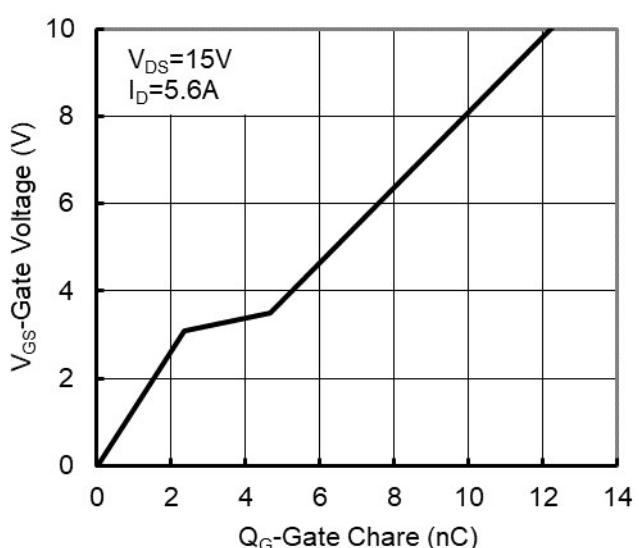
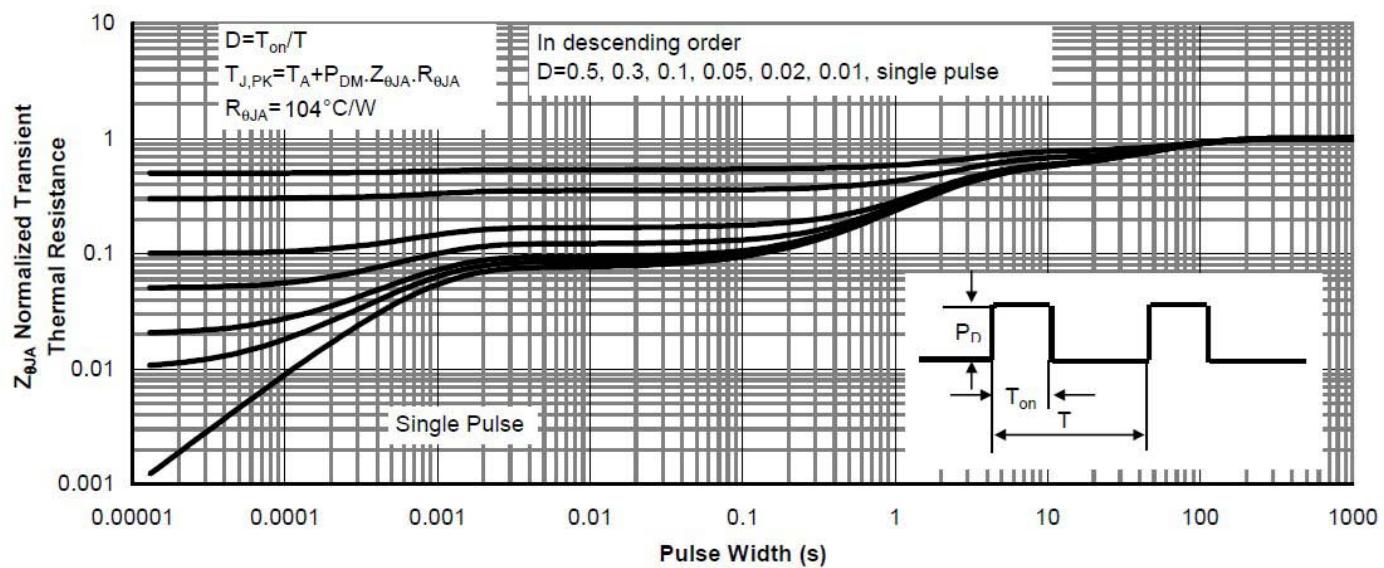
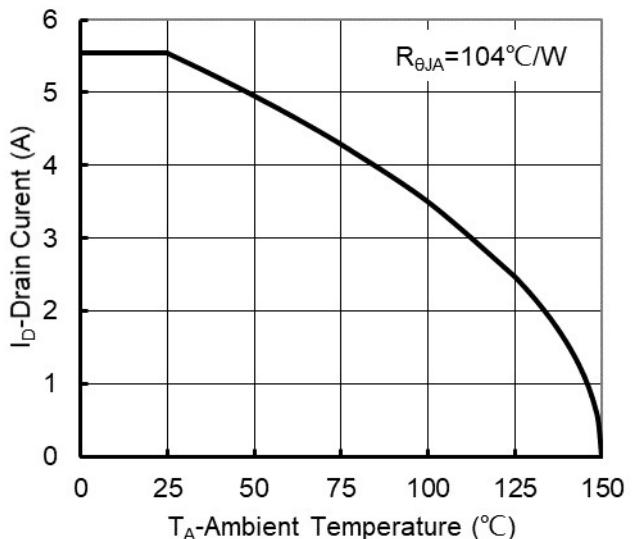
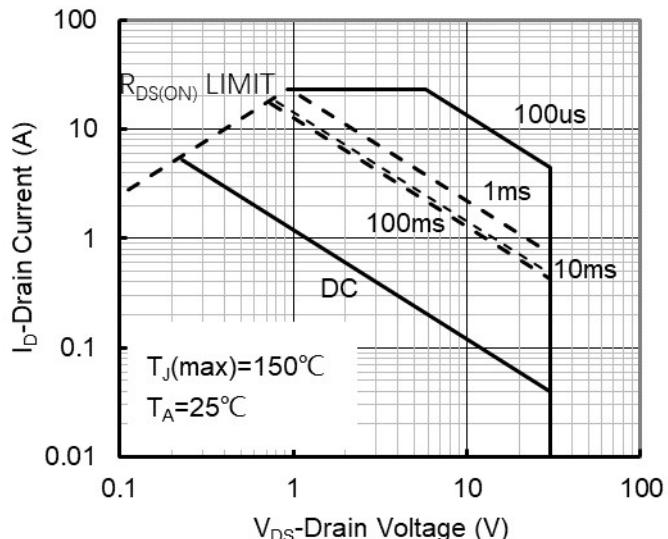
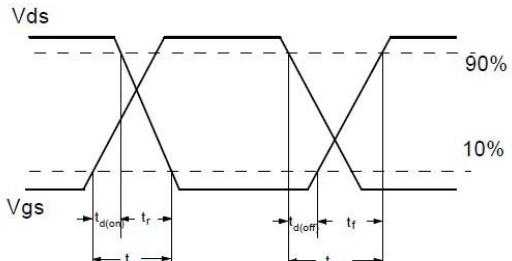
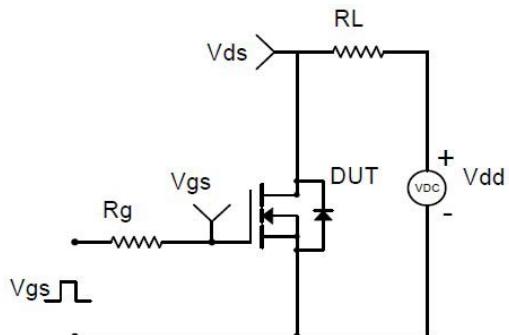


Figure 6. Gate Charge

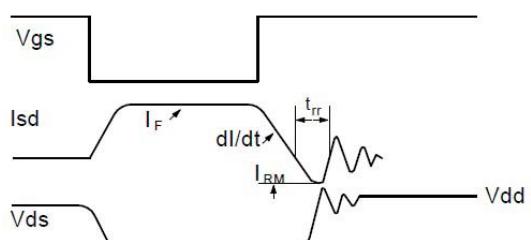
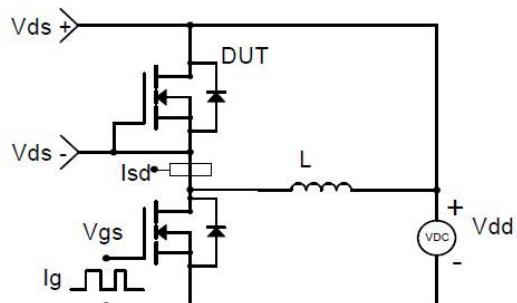
■ Typical Performance Characteristics(Con.)



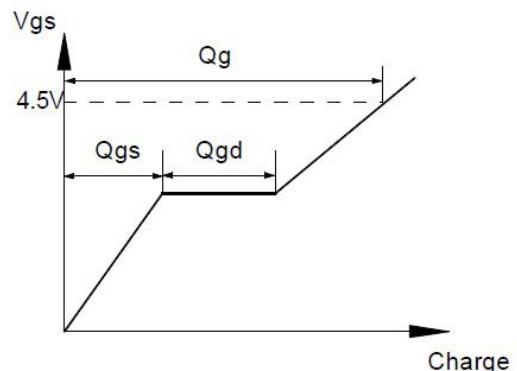
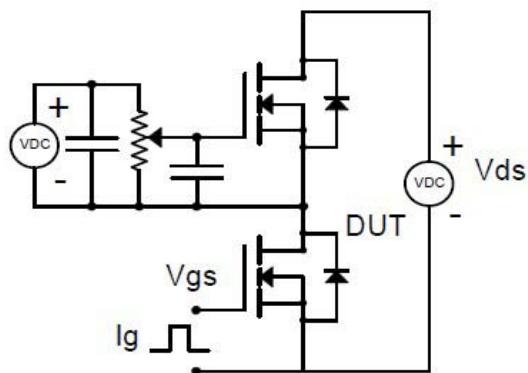
■ Test Circuits and Waveforms



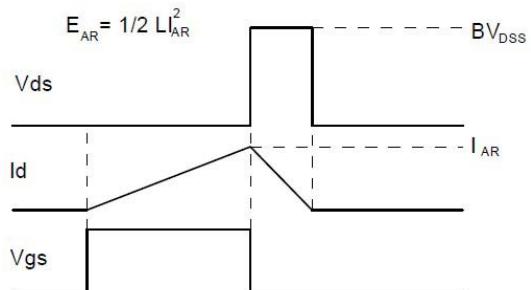
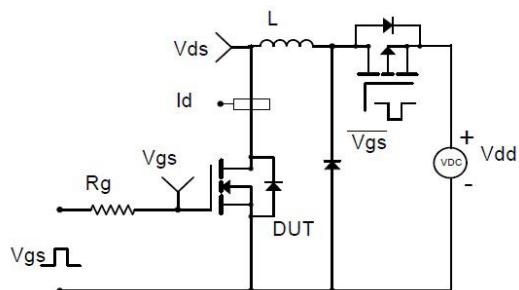
Resistive Switching Test Circuit & Waveforms



Diode Recovery Test Circuit & Waveforms

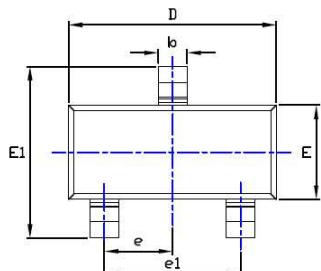


Gate Charge Test Circuit & Waveform

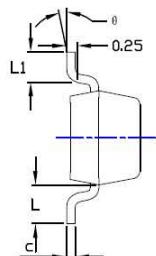


Unclamped Inductive Switching (UIS) Test Circuit & Waveforms

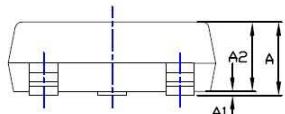
■ SOT-23 Package information



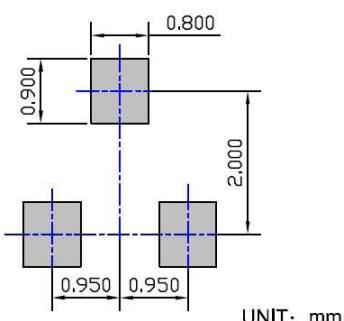
TOP VIEW



SIDE VIEW



SIDE VIEW



UNIT: mm

SUGGESTED SOLDER PAD LAYOUT

SYMBOL	INCHES			Millimeter		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.035	---	0.045	0.900	---	1.150
A1	0.000	---	0.004	0.000	---	0.100
A2	0.035	0.038	0.041	0.900	0.975	1.050
b	0.012	0.016	0.020	0.300	0.400	0.500
c	0.004	---	0.008	0.100	---	0.200
D	0.110	0.114	0.118	2.800	2.900	3.000
E	0.047	0.051	0.055	1.200	1.300	1.400
E1	0.089	0.094	0.100	2.250	2.400	2.550
e	0.037 TYP			0.950 TYP		
e1	0.071	0.075	0.079	1.800	1.900	2.000
L	0.022 REF			0.550 REF		
L1	0.012	0.016	0.020	0.300	0.400	0.500
θ	0°	---	8°	0°	---	8°

NOTE:

- 1.PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS,
- 2.TOLERANCE 0.1mm UNLESS OTHERWISE SPECIFIED.
- 3.THE PAD LAYOUT IS FOR REFERENCE PURPOSES ONLY.